

N-Channel Power MOSFET

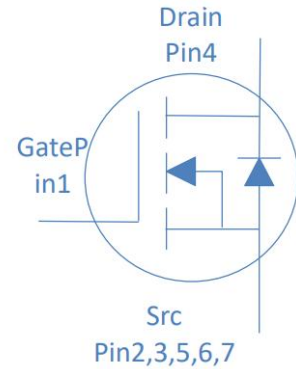
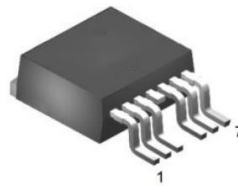
FEATURES

- Drain Current - I_D = 180A@ $T_C=25^{\circ}\text{C}$
- Drain Source Voltage - V_{DS} = 60V(Min)
- Static Drain-Source On-Resistance
- $R_{DS(on)}$ = 2.4m Ω (Max)@ V_{GS} = 10V

APPLICATIONS

- Switching applications
- Power tools
- Motor control

TO-263-7

Absolute Maximum Ratings($T_C=25^{\circ}\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DS}	Drain-Source Voltage	60	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous @ $T_C=25^{\circ}\text{C}$ $T_C=100^{\circ}\text{C}$	180 180	A
I_{DM}	Drain Current-Single Pulsed	720	A
P_D	Total Dissipation @ $T_C=25^{\circ}\text{C}$	300	W
T_{ch}	Max. Operating Junction Temperature	175	$^{\circ}\text{C}$
T_{stg}	Storage Temperature	-55~175	$^{\circ}\text{C}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	0.5	$^{\circ}\text{C/W}$
$R_{th(ch-a)}$	Channel-to-ambient thermal resistance	35	$^{\circ}\text{C/W}$

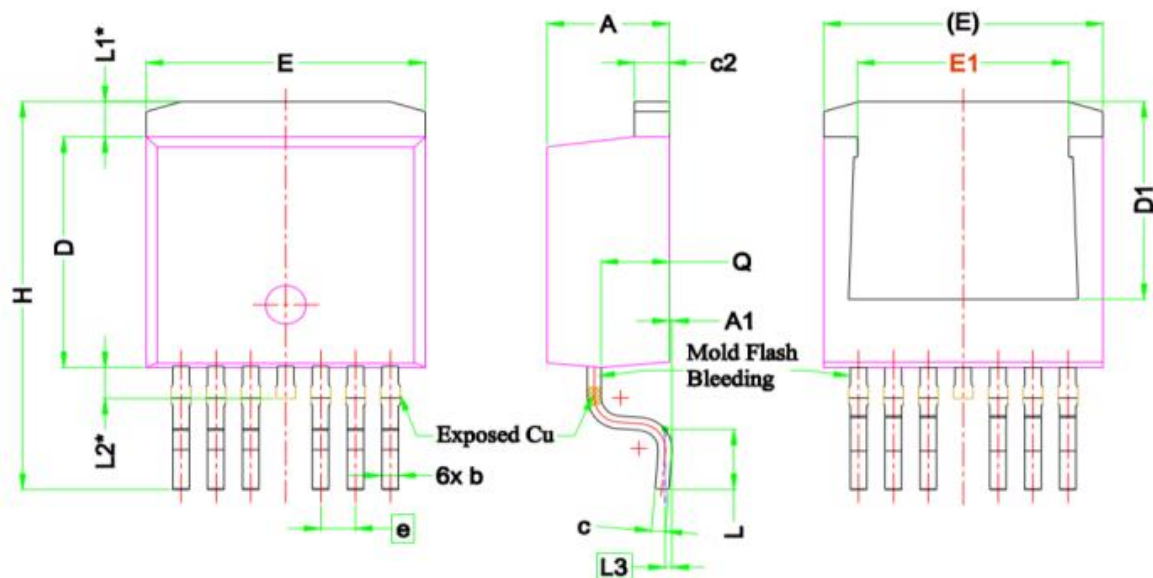
N-Channel Power MOSFET

ELECTRICAL CHARACTERISTICS (T_c=25°C)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 0.25mA	60	--	--	V
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 60V; V _{GS} = 0V; T _j =25°C V _{DS} = 60V; V _{GS} = 0V; T _j =125°C			1 100	μ A
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V; V _{DS} = 0V			± 100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = ±30V; I _D =0.25mA	2.0		4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =22.5A		1.7	2.4	mΩ
V _{SD}	Diode forward voltage	I _{SD} = 180A, V _{GS} = 0 V			1.4	V

N-Channel Power MOSFET

Package Dimensions (UNIT: mm):



SYMBOL	DIMENSIONS		
	MIN.	NOM.	MAX.
A	4.24	4.44	4.64
A1	0.00	0.10	0.25
b	0.50	0.60	0.70
c	0.40	0.50	0.60
c2	1.15	1.27	1.40
D	8.82	8.92	9.02
D1	6.86	7.65	—
E	9.96	10.16	10.36
E1	6.89	7.77	7.89
e	1.27 BSC		
H	14.61	15.00	15.88
L	1.78	2.32	2.79
L1	1.36 REF.		
L2	1.20 REF.		
L3	0.25 BSC		
Q	2.30	2.48	2.70

N-Channel Power MOSFET**PRODUCT DISCLAIMER**

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.